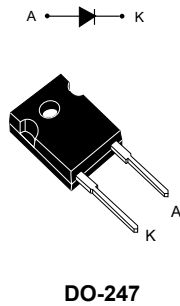



## Automotive 800 V, 60 A bridge rectifier diode



### Features

- AEC-Q101 qualified 
- Ultra low conduction losses
- Ultra-low reverse losses
- High junction temperature capability (+175 °C)
- $V_{RRM}$  guaranteed from -40 to +175 °C
- PPAP capable
- ECOPACK2 compliant

### Applications

- On board charger (OBC)
- Charging stations
- Bridge function

### Description

The high quality design of this diode has produced a device with consistently reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability like automotive applications.

Thanks to its ultra-low conduction losses, the **STBR6008-Y** is especially suitable for use as input bridge diode in battery chargers and charging stations.

#### Product status link

[STBR6008-Y](#)

#### Product summary

Symbol	Value
$I_{F(AV)}$	60 A
$V_{RRM}$	800 V
$T_j$	-40 to +175 °C
$V_F$ (typ.)	1.00 V

# 1 Characteristics

**Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)**

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage	$T_j = -40\text{ °C to }+175\text{ °C}$	800	V
$V_{RSM}$	Non-repetitive surge reverse voltage	$t_p = 10\text{ ms square}$	900	V
$I_{F(RMS)}$	Forward rms current		90	A
$I_{F(AV)}$	Average forward current	$T_C = 160\text{ °C}, \delta = 0.5\text{ square wave}$	60	A
$I_{FSM}$	Surge non repetitive forward current	$t_p = 10\text{ ms sinusoidal}$	500	A
$T_{stg}$	Storage temperature range		-65 to +175	°C
$T_j$	Operating junction temperature		-40 to +175	°C

**Table 2. Thermal parameters**

Symbol	Parameter	Typ. value	Unit
$R_{th(j-c)}$	Junction to case	0.20	°C/W

For more information, please refer to the following application note :

- AN5088 : Rectifiers thermal management, handling and mounting recommendations

**Table 3. Static electrical characteristics**

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R$	Reverse leakage current	$T_j = 25\text{ °C}$	$V_R = V_{RRM}$	-		5	$\mu\text{A}$
		$T_j = 150\text{ °C}$		-	25	250	
$V_F$	Forward voltage drop	$T_j = 25\text{ °C}$	$I_F = 60\text{ A}$	-	1.00	1.10	V
		$T_j = 150\text{ °C}$		-	0.88	0.97	

1. Pulse test:  $t_p = 5\text{ ms}, \delta < 2\%$

2. Pulse test:  $t_p = 380\text{ }\mu\text{s}, \delta < 2\%$

To evaluate the conduction losses, use the following equation:

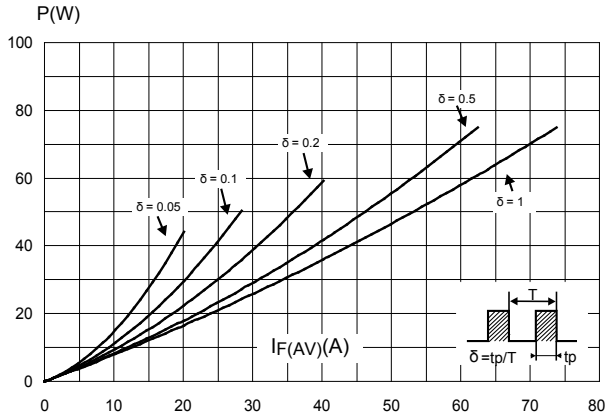
$$P = 0.75 \times I_{F(AV)} + 0.0036 \times I_{F(RMS)}^2$$

For more information, please refer to the following application notes related to the power losses:

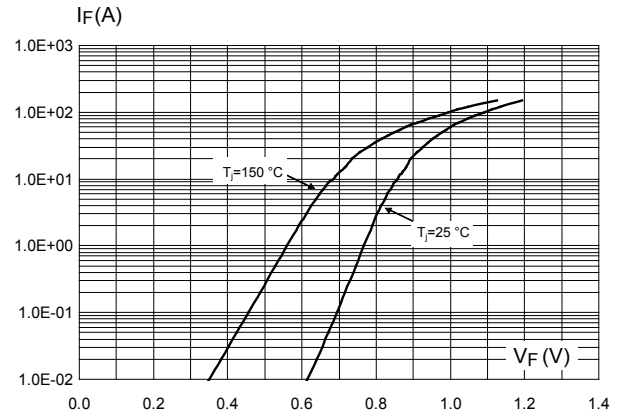
- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses in a power diode

### 1.1 Characteristics (curves)

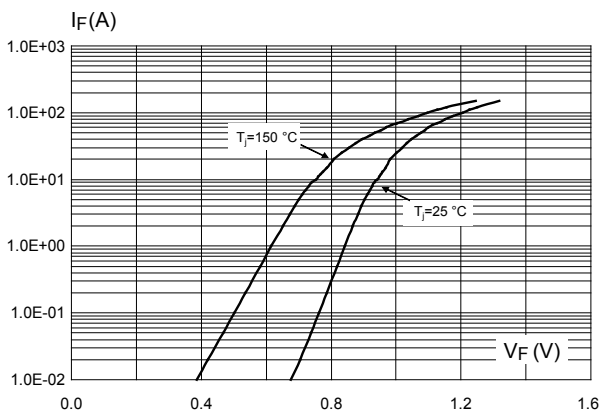
**Figure 1. Average forward power dissipation versus average forward current**



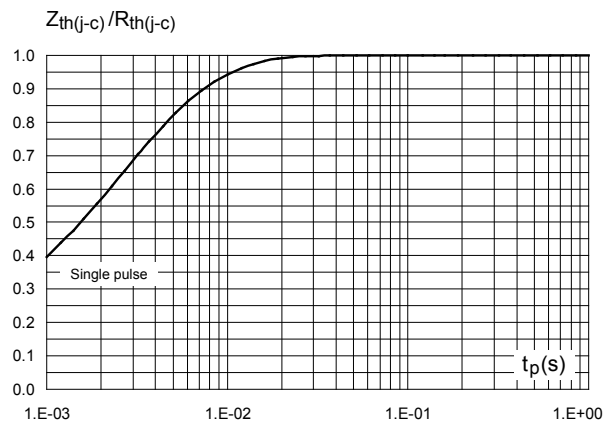
**Figure 2. Forward voltage drop versus forward current (typical values)**



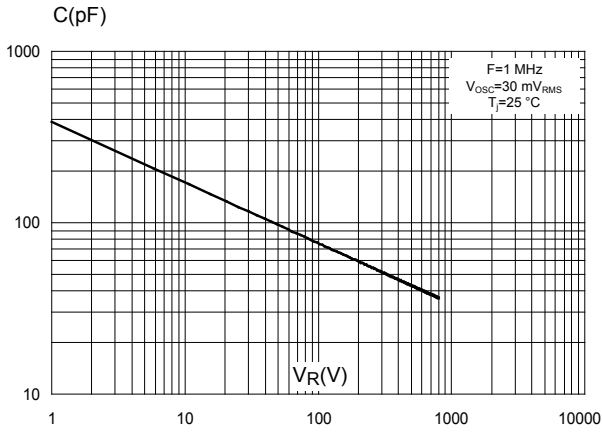
**Figure 3. Forward voltage drop versus forward current (maximum values)**



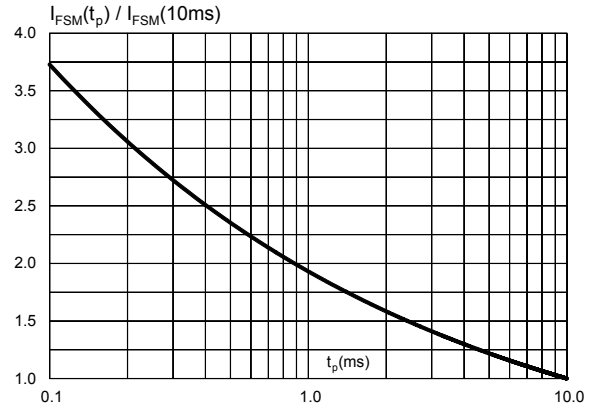
**Figure 4. Relative variation of thermal impedance junction to case versus pulse duration**



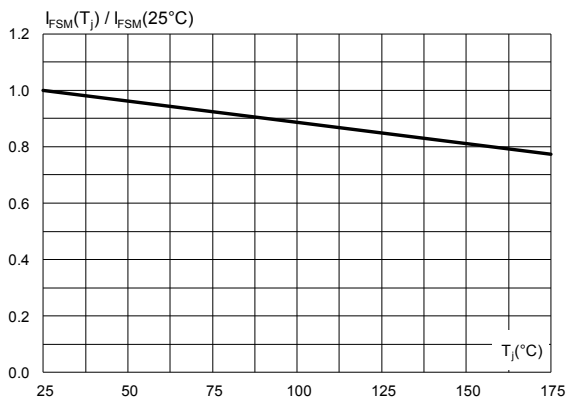
**Figure 5. Junction capacitance versus reverse voltage applied (typical values)**



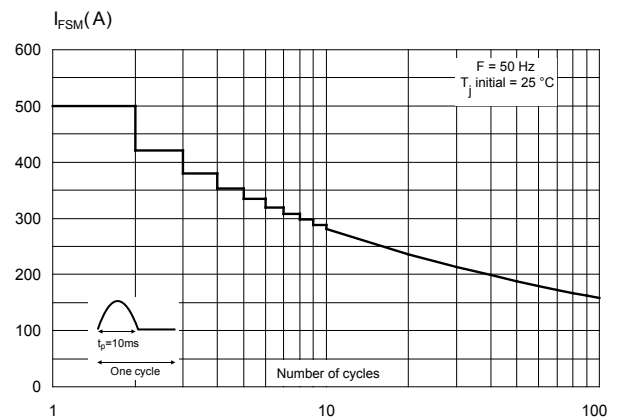
**Figure 6. Relative variation of non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)**



**Figure 7. Relative variation of non-repetitive peak surge forward current versus initial junction temperature (sinusoidal waveform)**



**Figure 8. Non repetitive surge peak forward current versus number of cycles**



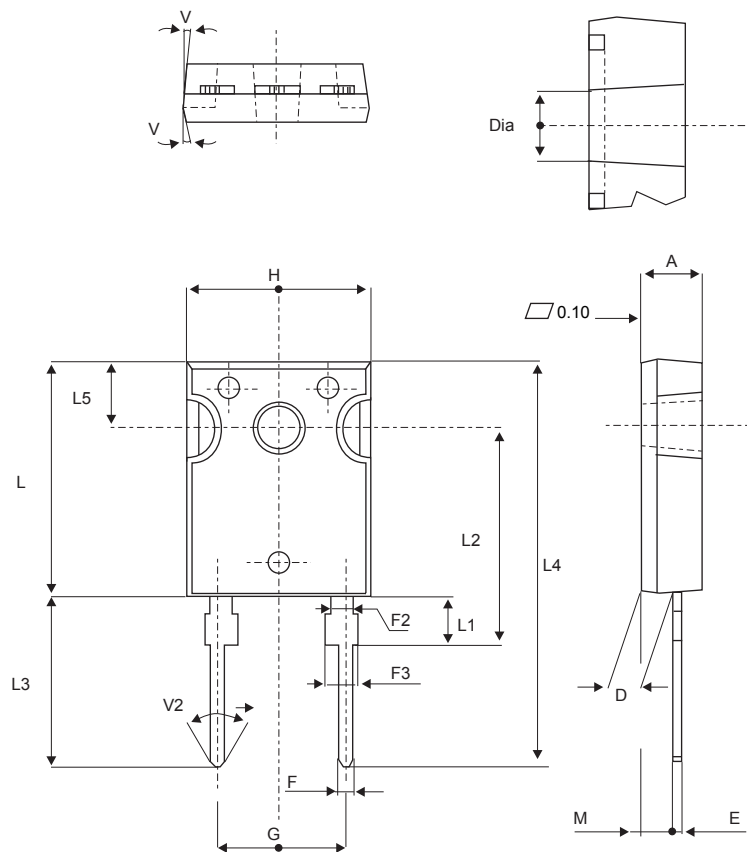
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 2.1 DO-247 package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N·m (DO-247)
- Maximum torque value: 1.0 N·m (DO-247)

**Figure 9. DO-247 package outline**



**Table 4. DO-247 package mechanical data**

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.85	5.15	0.191	0.203
D	2.20	2.60	0.086	0.102
E	0.40	0.80	0.015	0.031
F	1.00	1.40	0.039	0.055
F2	2.00 typ.		0.078 typ.	
F3	2.00	2.40	0.078	0.094
G	10.90 typ.		0.429 typ.	
H	15.45	15.75	0.608	0.620
L	19.85	20.15	0.781	0.793
L1	3.70	4.30	0.145	0.169
L2	18.50 typ.		0.728 typ.	
L3	14.20	14.80	0.559	0.582
L4	34.60 typ.		1.362 typ.	
L5	5.50 typ.		0.216 typ.	
M	2.00	3.00	0.078	0.118
V	5°		5°	
V2	60°		60°	
Dia.	3.55	3.65	0.139	0.143

### 3 Ordering information

**Table 5. Ordering information**

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STBR6008WY	STBR6008WY	DO-247	4.4 g	30	Tube

## Revision history

**Table 6. Document revision history**

Date	Revision	Changes
10-Jun-2019	1	First issue.



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